

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/777,973	02/11/2004	Yunlong Sun	50001/91:2 US 7445	
759	90 08/23/2006		EXAMINER	
Sandra K. Szczerbicki			ELVE, MARIA ALEXANDRA	
Suite 2600 900 SW Fifth Avenue		ART UNIT	PAPER NUMBER	
Portland, OR 97204-1268			1725	
		DATE MAILED: 08/23/2006		

Please find below and/or attached an Office communication concerning this application or proceeding.

			1			
		Application No.	Applicant(s)			
Office Action Summary		10/777,973	SUN ET AL.			
		Examiner	Art Unit			
		M. Alexandra Elve	1725			
 Period for	The MAILING DATE of this communication app Reply	pears on the cover sheet with the c	orrespondence address -			
WHICH - Extens after Si - If NO p - Failure Any rej	PRTENED STATUTORY PERIOD FOR REPLY HEVER IS LONGER, FROM THE MAILING DATE ions of time may be available under the provisions of 37 CFR 1.13 IX (6) MONTHS from the mailing date of this communication. It (6) MONTHS from the mailing date of this communication is period for reply is specified above, the maximum statutory period we to reply within the set or extended period for reply will, by statute, ply received by the Office later than three months after the mailing patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status	•					
1)⊠ F	Responsive to communication(s) filed on <u>26 Ju</u>	<u>ıne 2006</u> .	•			
	This action is FINAL . 2b) This action is non-final.					
3)□ S	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
C	closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	53 O.G. 213.			
Dispositio	on of Claims					
5)□ 0 6)図 0 7)□ 0	Claim(s) <u>1-25</u> is/are pending in the application. a) Of the above claim(s) is/are withdray Claim(s) is/are allowed. Claim(s) <u>1-25</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or	vn from consideration.				
Applicatio	n Papers					
10)⊠ TI A F	he specification is objected to by the Examine he drawing(s) filed on 11 February 2004 is/are Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction he oath or declaration is objected to by the Ex	e: a)⊠ accepted or b)□ objected drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority un	nder 35 U.S.C. § 119		•			
12)□ A a)□ 1 2 3	cknowledgment is made of a claim for foreign All b) Some * c) None of: Certified copies of the priority documents Copies of the certified copies of the priority documents Copies of the certified copies of the priority documents application from the International Bureau te the attached detailed Office action for a list of	s have been received. s have been received in Application rity documents have been received u (PCT Rule 17.2(a)).	on No ed in this National Stage			
Attachment(s	s) of References Cited (PTO-892)	4) ☐ Interview Summary	/PTO.413)			
2) D Notice	of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Da	ite			
	ation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date	5) Notice of Informal P 6) Other:	atent Application (PTO-152)			

DETAILED ACTION

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 1-25 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Applicant claims rapid removal of target material while retaining dimensional stability of the target material.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-2, 4-5, 8, 11-25 are rejected under 35 U.S.C. 102(b) as being anticipated by Cordingley et al. (USPAP 2002/0167581).

Cordingley et al. discloses an improved thermal based laser method for processing a predetermined microstructure formed on a substrate without causing undesirable changes in

Application/Control Number: 10/777,973

Art Unit: 1725

electrical and physical characteristics of the substrate or other structures formed on the substrate. Multi-material and layered materials and wafers are processed. Copper links are removed on multilevel devices. Additionally, microscopic holes can be drilled. Laser processing is thermal based. The laser energy used is about 60 to 70% of laser energy required for laser processing.

Page 3

A q-switched pulse laser may be used, as well as a mode-locked system. Fiber amplification is an option. IR, UV and green spectrum lasers are used to blow copper links. Wavelengths may be chosen based on the substrate properties, with the typically value being 1.047 um. Repetition rates range from 1uHz to 20KHz to 60 MHz (mode lock system). Beam spot, pulse width, energy pulse values are all selected to ensure optimal processing. Pulse widths of less than 5 nanoseconds are used (few picoseconds to nanoseconds). Multiple pulses may be used (259). In order to limit thermal diffusion and hence negate substrate damage, pulse energies range from 0.1 microjoules to 3 microjoules. The position and depth of focus of the beam is selected to ensure that the substrate is processed without creating undesirable changes to other materials. Additionally, the system normalizes the defocus function. Figure 15a shows the focusing optics and beam guidance. (abstract, figures, 0005, 0007, 0009, 0016, 0024-0029, 0034, 0036, 0046, 0057-0058, 0083-0091, 0095-0096, 0106, 0109, 0112-0113, 0115, 0117-0120, 0122, 0125-0126, 0134, 0137-0152, 0165, 0190, 0193, 0195-0196, 0198, 0200-0201, 0204, 0210, 0220-0221, 0226)

Application/Control Number: 10/777,973

Art Unit: 1725

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Cordingley et al., as stated in the above paragraph and further in view of Owen et al. (USPN 5,841,099).

Cordingley et al. teaches drilling holes, but not blind vias.

Owen et al. discloses the use of a q-switched laser to drill vias and blind vias in multilayer materials (metallic and dielectric layers). (abstract)

It would have been obvious to one of ordinary skill in the art at the time of the invention to drill blind vias, as taught by Owen et al. in the Cordingley et al. system because this is merely a specific type of hole drilling.

Claims 9-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cordingley et al., as stated in the above paragraph and further in view of Fahey et al. (WO 03/002289 A1).

Cordingley et al. discloses the processing of wafers but not dicing.

Fahey et al. discloses the dicing or wafers using an IR laser with differing wavelengths.

(abstract)

It would have been obvious to one of ordinary skill in the art at the time of the invention to dice wafers, as taught by Fahey et al. in the Cordingley et al. system because it is merely a specific type of wafer processing.

Claims 6-7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cordingley et al. as stated in the above paragraph and further in view of the following.

Cordingley et al. teaches a range of wavelengths, which are selected, based on the processing operations needs. It is well settled that where patentability is predicated upon a change in a condition of prior process, that is, the wavelength, the change must be at least critical, that is, it must lead to a new and unexpected result. The applicant has the burden of providing such proof of criticality. Note <u>In re Aller</u> et al. 105 USPQ 223.

Response to Arguments

Applicant's arguments filed 6/26/06 have been fully considered but they are not persuasive.

Applicant argues that the prior art does not disclose separate steps and thermal energy is not addressed. The examiner respectfully disagrees because instant claims do not specifically disclose separate steps. Furthermore, Cordingley et al. is a thermal based laser method and thus heating is inherent in the application of the laser. In addition, the sequence in a process is not patentable, In re Gibson 5 USPQ 231, 232 (1930) and the substitution of one known equivalent technique for another may be obvious even if the prior art does not expressly suggest the substitution. In re Leshin 125 USPQ 416, Lyon v. Bausch & Lomb 106 USPQ 1, Graver Tank & Manufacturing Co. v. Linde Air Products Co. 85 USPQ 328.

Application/Control Number: 10/777,973

Art Unit: 1725

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to M. Alexandra Elve whose telephone number is 571-272-1173. The examiner can normally be reached on 6:30-3:00 Monday to Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Pat Ryan can be reached on 571-272-1292. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

August 21, 2006.

M. Alexandra Elve

Primary Examiner 1725

Page 6